

Total No. of Questions – [3]

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PAPER CODE	V113-2032 (B)
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MAY 2022 (INSEM+ ENDSEM) EXAM
F.Y. B. TECH. (SEMESTER - II)
COURSE NAME: BASIC ELECTRONICS ENGINEERING
COURSE CODE: ET10203B
(PATTERN 2020)

Time: [2Hr]

[Max. Marks: 60]

(*) Instructions to candidates:

- 1) Figures to the right indicate full marks.
- 2) Use of scientific calculator is allowed
- 3) Use suitable data where ever required

Q.1 Solve the following

- i) If the a.c. input to a half-wave rectifier is an r.m.s value of $200/\sqrt{2}$ volts, then diode PIV rating is----- [2]
 - a) $200/\sqrt{2}$ V
 - b) 200 V
 - c) $400\sqrt{2}$ V
 - d) 400 V
- ii) Two LED's are connected in series along with limiting resistance. It is supplied with 12 V DC supply and drop across each LED is 1.5 V, the value of limiting resistance for 10 mA current is----- [2]
 - a) $400\ \Omega$
 - b) $750\ \Omega$
 - c) $900\ \Omega$
 - d) $600\ \Omega$
- iii) In Center tapped full wave rectifier, if the peak value of secondary voltage is 25 V then the peak value of the output voltage is ____ [2]
 - a) 24.3 V
 - b) 11.8 V
 - c) 25.7 V
 - d) 12.5 V
- iv) What is the average value of full wave rectifier, for $V_p(\text{out}) = 50\text{V}$ [2]
 - a) 31.85 V
 - b) 45.65 V
 - c) 50.7 V
 - d) 15.9 V

- v) Each diode in a center-tapped full-wave rectifier is _____-biased and conducts for _____ of the input cycle. [2]
 a) forward, 90 degrees
 b) forward, 180 degrees
 c) reverse, 90 degrees
 d) reverse, 360 degrees
- vi) In Half Wave Rectifier, if peak value of output is 12.5 V, then the peak value of it's input is _____. [2]
 a) 12.5 V
 b) 22.5 V
 c) 11.8 V
 d) 13.2 V
- vii) In Center tapped FWR, if the peak value of secondary voltage is 50 V then the peak value of the output voltage is _____. [2]
 a) 24.3 V
 b) 20.8 V
 c) 50.7 V
 d) 49.3 V
- viii) The current flowing through the Photo diode without illumination of light in reverse bias mode is called as _____. [2]
 a) reverse current
 b) dark current
 c) forward current
 d) pinch off current
- ix) Determine value of collector current I_c , for $\beta=180$ and base current $I_B=25 \mu A$. [2]
 a) 10 mA
 b) 0.45 mA
 c) 4.5 mA
 d) 45 μA
- x) For voltage divider biasing circuit, if $R_1=1.5 K\Omega$ $R_2=680 \Omega$, $V_{CC}=10V$. What is the value of V_B (voltage at Base terminal) ? [2]
 a) 3.12 V
 b) 6.23 V
 c) 10 V
 d) 0.7 V
- xi) In Common Emitter amplifier, if base current is 40 μA and beta is 50. What is the value of collector current? [2]
 a) 20 mA
 b) 200 μA
 c) 2 A
 d) 2 mA

- xii) In voltage divider biasing circuit using BJT, if $V_E=1.4\text{ V}$ and $R_E=700\ \Omega$. What is the value of emitter current I_E ? [2]
 a) 1.4 mA
 b) 2 A
 c) 2 mA
 d) 20 mA
- xiii) What is the phase shift between input and output signal for BJT Common Emitter configured amplifier? [2]
 a) 90°
 b) 180°
 c) 270°
 d) 360°
- xiv) The biasing circuit has a stability factor of 35. If due to temperature change, I_{CBO} changes by $2\ \mu\text{A}$, then I_C will change by [2]
 a) $7\ \mu\text{A}$
 b) $7.2\ \mu\text{A}$
 c) $0.7\ \mu\text{A}$
 d) $70\ \mu\text{A}$
- xv) In transistor amplifier circuit, if 14 V of V_{CC} is applied, then for maximum amplification of input signal at its output, what value of V_{CE} is required? [2]
 a) 14 V
 b) 0.7 V
 c) 7 V
 d) 1.4 V

Q.2

Solve any three out of four

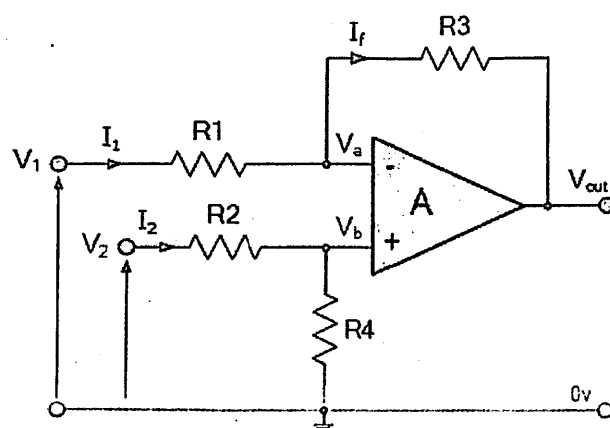
- a) Sketch the internal construction of an n-channel Enhancement type of MOSFET and draw the output I-V characteristics of n-channel E-MOSFET. [5]
- b) Draw Common Source amplifier circuit with voltage divider biasing using n-channel E-MOSFET and explain the significance of coupling and bypass capacitors connected in the circuit. [5]
- c) Calculate V_{GS} and V_{DS} for the MOSFET with voltage divider bias circuit, given parameters are $R_1 = 100\text{ K}\Omega$, $R_2 = 15\text{ K}\Omega$, $R_D = 200\ \Omega$, $V_{DD} = 24\text{ V}$. Assume this particular MOSFET has minimum values of $I_{D(on)} = 200\text{ mA}$ at $V_{GS} = 4\text{ V}$ and $V_{GS(th)} = 2\text{ V}$. [5]
- d) Sketch the forward characteristics of SCR for different values of gate current and explain turn on process of it. [5]

Q.3

Solve any three out of four

- a) Sketch the block diagram of op-amp and explain the working of each block. [5]

- b) Compare between Inverting and non inverting amplifier configurations of an op-amp. [5]
- c) Draw the diagram of inverting amplifier configuration using an op-amp and derive the expression for its gain. [5]
- d) For the given Op-amp as sub-tractor circuit diagram, the values mentioned are $V_1=2V$, $V_2=5V$, $R_1=2\text{ K}\Omega$, $R_2=2\text{ K}\Omega$, $R_3=10\text{ K}\Omega$, $R_4=4\text{ K}\Omega$. Find the output voltage V_{out} . [5]



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